

RoHS Compliant



MASWSS0204 V1

GaAs SPDT 2.7 V High Power Switch DC - 3.0 GHz

Features

- Low Voltage Operation: 2.7 V
- High IP3: +56 dBm
- Low Insertion Loss: 0.30 dB at 1 GHz
- High Isolation: 25 dB at 1 GHz
- 0.5 micron GaAs PHEMT Process
- Lead-Free SC70 Package
- 100% Matte Tin Plating over Copper
- Halogen-Free "Green" Mold Compound
- 260°C Reflow Compatible
- RoHS* Compliant Version of MASWSS0117

Description

M/A-COM's MASWSS0204 is a GaAs PHEMT MMIC single pole double throw (SPDT) high power switch in a low cost SC70 six lead package. The MASWSS0204 is ideally suited for applications where high power, low control voltage, low insertion loss, high isolation, small size and low cost are required.

Typical applications are for CDMA handset systems that connect separate transceiver and/or GPS functions to a common antenna, as well as other related handset and general purpose applications. The MASWSS0204 can be used in all systems operating up to 3 GHz requiring high power at low control voltage.

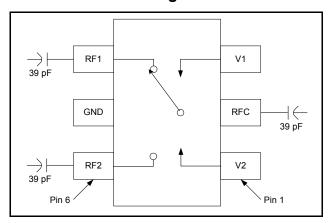
The MASWSS0204 is fabricated using a 0.5 micron gate length GaAs PHEMT process. The process features full passivation for performance and reliability.

Ordering Information

Part Number	Package
MASWSS0204	Bulk Packaging
MASWSS0204TR-3000	3000 piece reel
MASWSS0204SMB	Sample Test Board

Note: Reference Application Note M513 for reel size information

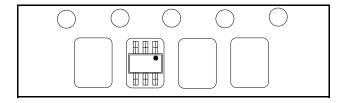
Functional Block Diagram



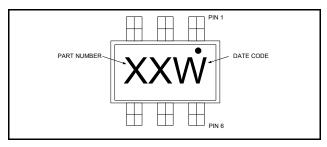
Pin Configuration

Pin No.	Pin Name Description		
1	V2	Vcontrol 2	
2	RFC	RF Common	
3	V1	Vcontrol 1	
4	RF1	RF Port 1	
5	GND	RF Ground	
6	RF2	RF Port 2	

MASWSS0204 orientation in tape



MASWSS0204 Device Marking



^{*} Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

- M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298



RoHS Compliant



MASWSS0204

GaAs SPDT 2.7 V High Power Switch DC - 3.0 GHz

Electrical Specifications: $T_A = 25^{\circ}C$, Vc = 0 V/2.7 V, $Z_0 = 50 Ohms^{-1}$

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Insertion Loss ²	DC – 1 GHz 1 – 2 GHz 2 - 3 GHz	dB dB dB	_ _ _	0.30 0.35 0.35	0.65 — —
Isolation	DC – 1 GHz 1 – 2 GHz 2 - 3 GHz	dB dB dB	23 — —	25 19 15	_ _ _
Return Loss	DC – 3 GHz	dB	_	20	_
IP3	825 MHz Two Tone, +24 dBm Total Pin, 5 MHz Spacing	dBm	_	56	_
Cross Modulation	For Cell Band: Two-tone signal input: Tx1 = +22 dBm @ 820 MHz, Tx2 = +22 dBm @ 821 MHz, RX interfere = -23 dBm @ 869 MHz.	dBm	_	-99	_
	For PCS Band: Two-tone signal input: Tx1 = +18 dBm @ 1880 MHz, Tx2 = +18 dBm @ 1881 MHz, RX interfere = -23 dBm @ 1960 MHz.	dBm	_	-94	_
P0.1dB	1 GHz	dBm	_	38	_
Trise, Tfall	10% to 90% RF, 90% to 10% RF	nS	_	70	_
Ton, Toff	50% control to 90% RF, 50% control to 10% RF	nS	_	100	_
Transients	In Band	mV	_	25	_
Control Current	Vc = 2.7 V	μΑ	_	5	20

^{1.} For positive voltage control, external DC blocking capacitors are required on all RF ports.

Absolute Maximum Ratings 3,4

Parameter	Absolute Maximum
Input Power (0.5 - 3 GHz, 3 V Control)	+38 dBm
Operating Voltage	+8.5 volts
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

- 3. Exceeding any one or combination of these limits may cause permanent damage to this device.
- 4. M/A-COM does not recommend sustained operation near these survivability limits.

Truth Table 5,6,7

V1	V2	ANT-RF1	ANT - RF2
1	0	On	Off
0	1	Off	On

- For positive voltage control, external DC blocking capacitors are required on all RF ports.
- Differential voltage, V(state 1) V(state 0), must be +2.7 V minimum, but must not exceed 8.5 V.
- 7. 0 = -5 V to +2.3 V, 1 = -2.3 V to +5 V.

^{2.} Insertion loss can be optimized by varying the DC blocking capacitor value, e.g. 1000 pF for 100 MHz - 1 GHz, 39 pF for 0.5 GHz - 3 GHz.

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298



RoHS Compliant

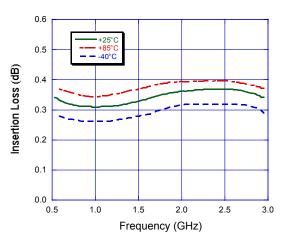


MASWSS0204 V1

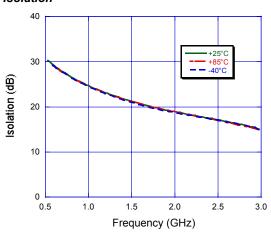
GaAs SPDT 2.7 V High Power Switch DC - 3.0 GHz

Typical Performance Curves, 39 pF

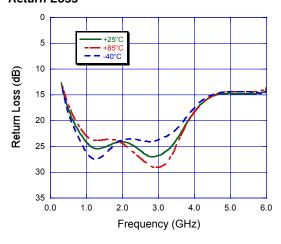
Insertion Loss



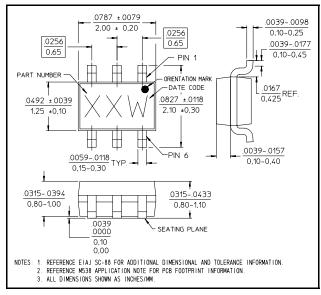
Isolation



Return Loss



Lead-Free SC70 Plastic Package[†]



Reference Application Note M538 for lead-free solder reflow recommendations.

Qualification

Qualified to M/A-COM specification REL-201, Process Flow -2.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

information.

M/A-COM Inc. and its affiliates reserve the right to make changes to the

North America Tel: 800.366.2266 / Fax: 978.366.2266

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298